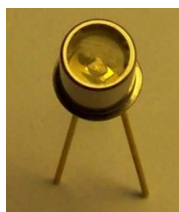




## SG01L18-ISO



Our SiC photodiodes feature extreme radiation hardness, low noise and a high visible blindness.

### Features:

- Broadband UVA-UVB-UVC Photodiode in TO18 hermetic metal housing
- Anode and cathode with insulated pins, one additional ground pin
- Silicon Carbide Chip guarantees extreme radiation hardness
- Chip dimensions 1 × 1 mm<sup>2</sup> with 0.96 mm<sup>2</sup> active area
- Non sensible for visible light ( $S_{280nm} / S_{400nm} > 10^4$ ), no filters needed
- Chip manufacturer: Cree Research Inc., U.S.A.

SiC Photodiodes from our series SG01XXX are also available with these features

<i>Photodiode description</i>	<i>Order Code</i>
0.054mm <sup>2</sup> SiC-Photodiode, TO18-housing with 2 Pins	SG01S
0.54mm <sup>2</sup> SiC-Photodiode, TO39-housing with 2 Pins	SG01S-5
like SG01S aber Temperaturfest bis 170°C	SG01S-HT
like SG01S but with 3 Pins in a row, 2 pins insulated, 1 pin grounded	SG01S-ISO
like SG01S but only sensible in the UVC area	SG01S-C18
like SG01S-5 but only sensible in the UVC area	SG01S-C
special photodiode in TO18 for Erythema measurements, DIN5050	EryF*
0.2 mm <sup>2</sup> SiC-Photodiode, TO18-housing with 2 pins	SG01M
0.2 mm <sup>2</sup> SiC-Photodiode, TO39, only sensible in the UVC area	SG01M-C
0.2 mm <sup>2</sup> SiC-Photodiode, TO39 with concentrating lens giving 4mm <sup>2</sup> 'virtual' active area	SG01M-Lens
0.96 mm <sup>2</sup> SiC Photodiode, TO39-housing with 2 Pins	SG01L-5
0.96 mm <sup>2</sup> SiC Photodiode, TO18-housing with 2 Pins	SG01L-18
like SG01L-5 but only sensible in the UVC area	SG01L-C
like SG01S with short cap	SG01SS
like SG01L-18 with 3 pins in 90°-orientation, 2 insulated, 1 ground	SG01L-18-ISO

Please also consider our product series

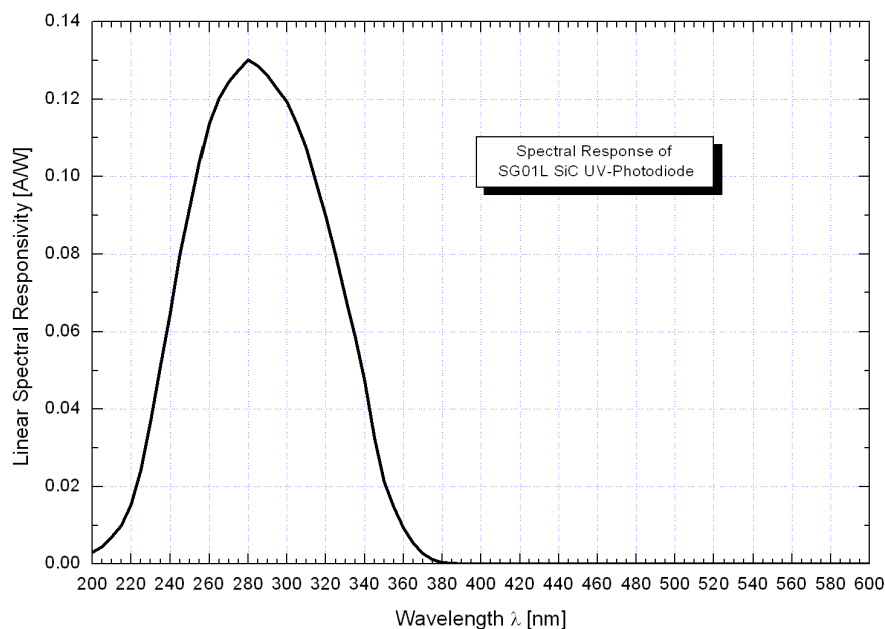
- UV-Sensor Probes
- UV-Monitors & Controllers
- UV-Handhelds



## SG01L18-ISO

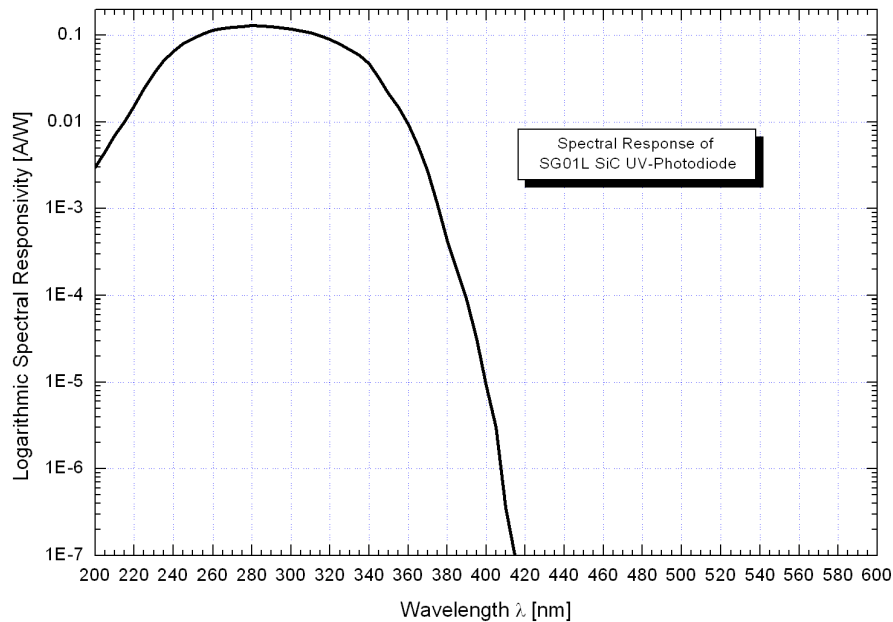
**Technical Specification (Ta = 25 °C)**

Parameter	Symbol	Wert	Einheit
Operating Temperature	T <sub>opt</sub>	-25 ... +70	°C
Reverse Voltage	V <sub>Rmax</sub>	20	V
Active area	A	0.96	mm <sup>2</sup>
Dark current at 1V bias	I <sub>d</sub>	5	fA
Capacitance	C	200	pF
Current at medium radiation	I <sub>0</sub>	ca. 800	nA
Max. of spectral sensitivity	S <sub>max</sub>	0.13	AW-1
Wavelength of max. sensitivity	λ <sub>Smax</sub>	280	nm
Sensitivity range (S=0.1*S <sub>max</sub> )	–	220 - 360	nm

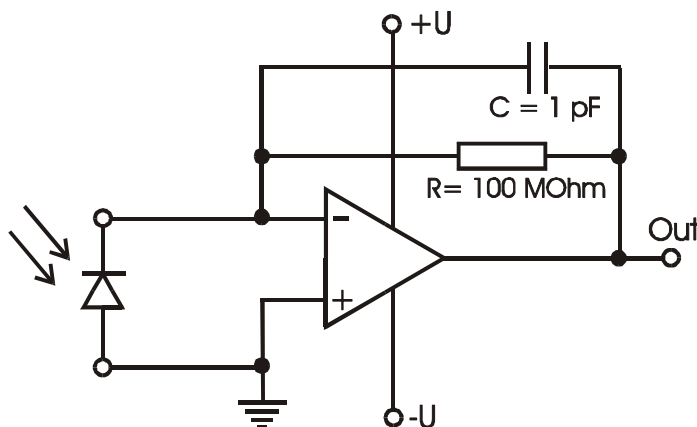
**Linear spectral response**

## SG01L18-ISO

### Logarithmic spectral response



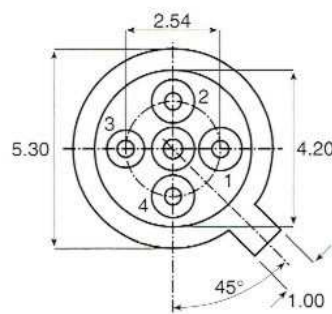
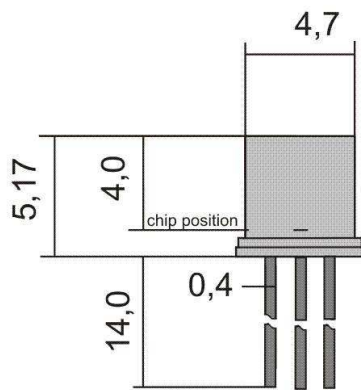
### Circuit example using OPA336





**SG01L18-ISO**

***Dimensions and pin layout***



top view  
1 Cathode  
2 Anode  
3 Ground  
4 pin not present